Unit: mm

0.22^{+0.10} (0.13 (b) 0.13 (c)

AN48810B

Low current consumption, high sensitivity CMOS Hall IC One-way magnetic field operation

Overview

The AN48810B is a Hall IC (a magnetic sensor) which has 2 times or more sensitivity and a low current consumption of about one three-hundredth compared with our conventional one.

In this Hall IC, a Hall element, a offset cancel circuit, an amplifier circuit, a sample and hold circuit, a Schmidt circuit, and output stage FET are integrated on a single chip housed in a small package by IC technique.

■ Features

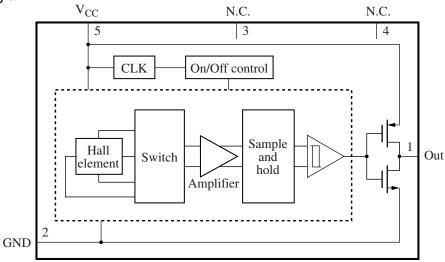
- High sensitivity (6 mT max.) due to offset cancel circuit and a new sample and hold circuit
- Small current by using intermittent action
- Small package (SMD)
- CMOS inverter output

■ Applications

• Flip type cellular phone, digital video camera

SMINI-5DA (Lead-free package)

■ Block Diagram



Note) The magnetism detection time should be longer than one intermittent action cycle (On = $200~\mu s$ and Off = 51~ms).

■ Pin Descriptions

Pin No.	Symbol	Description	Pin No.	Symbol	Description
1	Out	Output	4	N.C.	
2	GND	Ground	5	V _{CC}	Power supply
3	N.C.				

Hall IC AN48810B

■ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit	
Supply voltage	V _{CC}	5	V	
	V _{OUT}	5	V	
Output current	I _O	15	mA	
Power dissipation	P_{D}	60	mW	
Operating ambient temperature	T _{opr}	-20 to +75	°C	
Storage temperature	T _{stg}	-55 to +125	°C	

Note) 1. Except for the operating ambient temperature and storage temperature, all ratings are for $T_a = 25^{\circ}$ C.

- 2. The reverse insertion of this IC will cause its breakdown.
- 3. It will operate normally in several tens of ms after power on.
- 4. This IC is not suitable for car electrical equipment.

■ Recommended Operating Range

Parameter	Symbol	Range	Unit
Supply voltage	V _{CC}	2.5 to 3.5	V

■ Electrical Characteristics at T_a = 25°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Operating magnetic flux density 1	B _{H-L}	$V_{CC} = 3 \text{ V}$	_	_	6	mT
Operating magnetic flux density 2	B _{L-H}	$V_{CC} = 3 \text{ V}$	0.5		_	mT
Hysteresis width	BW	$V_{CC} = 3 \text{ V}$	_	1.2		mT
Output voltage 1	V _{OL}	$V_{CC} = 3 \text{ V}, I_{O} = 2 \text{ mA}, B = 6 \text{ mT}$		0.1	0.3	V
Output voltage 2	V _{OH}	$V_{CC} = 3 \text{ V}, I_{O} = -2 \text{ mA}, B = 0.5 \text{ mT}$	2.7	2.9	_	V
Supply current 1	I _{CCON}	$V_{CC} = 3 \text{ V}, B = 0.5 \text{ mT}$		2	_	mA
Supply current 2	I_{CCOFF}	$V_{CC} = 3 \text{ V}, B = 0.5 \text{ mT}$		3		μΑ
Supply current 3	I _{CCAVE}	$V_{CC} = 3 \text{ V}, B = 0.5 \text{ mT}$		10	15	μΑ

Note) 1. Symbol $B_{H\text{-}L}$ stands for the operating magnetic flux density where its output level varies from high to low.

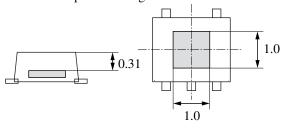
- 2. Symbol B_{L-H} stands for the operating magnetic flux density where its output level varies from low to high.
- 3. $I_{CC_{ON}}$ is a consumption current when the magnetism detection system is on, and $I_{CC_{OFF}}$ is that when the magnetism detection system is off. One magnetism detection cycle is On = 200 μ s and Off = 51 ms. $I_{CC_{AVE}}$ is an average consumption current.

■ Technical Data

• Position of a Hall element (unit in mm)

Distance from a package surface to sensor part: 0.31 mm (reference value)

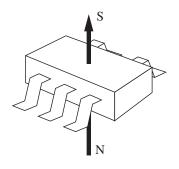
A Hall element is placed on the shaded part in the figure.

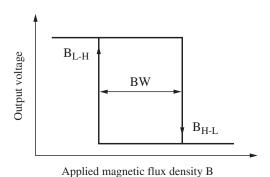


AN48810B Hall IC

■ Technical Data (continued)

• Magneto-electro conversion characteristics

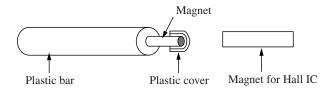




Direction of applied magnetic field

Operating magnetic flux density

Simple polarity distinction method of mounting magnet to product incorporating Hall IC

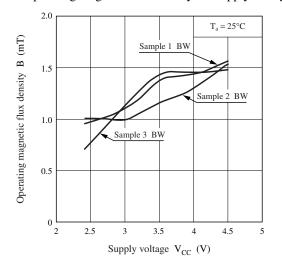


A magnet, which is used in pair with a Hall IC, can be mounted to a product incorporating a built-in Hall IC (e.g., a cellular phone) smoothly and correctly with a simple tool. The polarity of the magnet (hereafter referred to as Hall IC magnet) will be automatically discriminated.

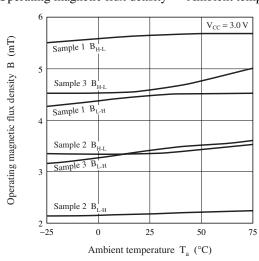
This tool is a plastic bar, one end of which is attached with a small magnet (hereafter referred to as plastic bar magnet), as shown in the above illustration. The plastic bar magnet, the polarity of which is known, is secured on the bar with a plastic cover. When the plastic bar magnet is located close to the Hall IC magnet, the Hall IC magnet will be attracted to the plastic bar magnet. The contact side of the Hall IC magnet is different in polarity from that of the plastic bar magnet. As a matter of course, the polarity of the Hall IC magnet will be known then. The Hall IC magnet can be mounted to the appliance in this state. The attraction force of the plastic bar magnet is rather weak due to the plastic cover on it. Therefore, the plastic bar can be separated from the Hall IC magnet with ease after the Hall IC magnet is mounted properly.

• Main characterisitcs

Operating magnetic flux density — Supply voltage



Operating magnetic flux density — Ambient temperature

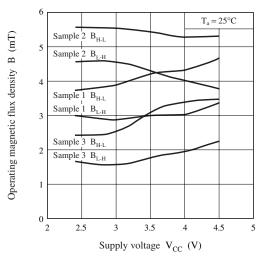


Hall IC AN48810B

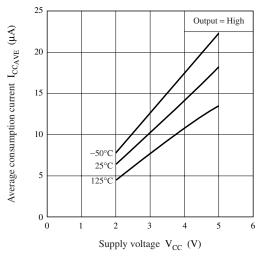
■ Technical Data (continued)

Main characterisitcs

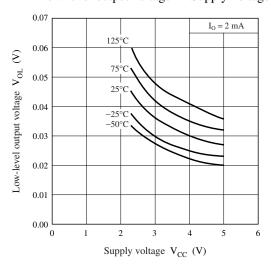
Operating magnetic flux density — Supply voltage



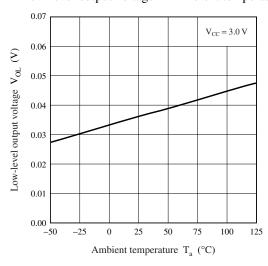
Average consumption current — Supply voltage



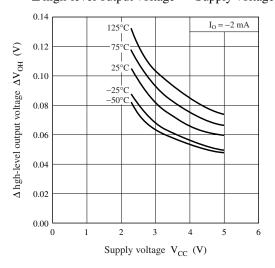
Low-level output voltage — Supply voltage



Low-level output voltage — Ambient temperature



 Δ high-level output voltage — Supply voltage



 Δ high-level output voltage — Ambient temperature

